



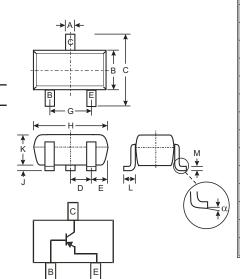
PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (MMST4401)
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking (See Page 2): K3T
- Ordering & Date Code Information: See Page 2
- Weight: 0.006 grams (approximate)



SOT-323								
Dim	Min	Max						
Α	0.25	0.40						
В	1.15	1.35						
С	2.00	2.20						
D	0.65 N	ominal						
E	0.30	0.40						
G	1.20	1.40						
Н	1.80	2.20						
J	0.0	0.10						
K	0.90	1.00						
L	0.25	0.40						
М	0.10	0.18						
α	0°	8°						
All Dimensions in mm								

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	MMST4403	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current - Continuous (Note 1)	Ic	-600	mA
Power Dissipation (Note 1)	P _d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ heta JA}$	625	K/W
Operating and Storage and Temperature Range	T _j , T _{STG}	-55 to +150	°C

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

- No purposefully added lead.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com./products/lead_free/index.php.
- 4. Product manufactured with Date Code 0609 (week 9, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0609 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

何"MMST4403-7cha/提起i鏡c	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	_	V	$I_C = -100 \mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40	_	V	I _C = -1.0mA, I _B = 0	
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	_	V	$I_E = -100 \mu A, I_C = 0$	
Collector Cutoff Current	I _{CEX}	_	-100	nA	$V_{CE} = -35V, V_{EB(OFF)} = -0.4V$	
Base Cutoff Current	I _{BL}	_	-100	nA	$V_{CE} = -35V, V_{EB(OFF)} = -0.4V$	
ON CHARACTERISTICS (Note 5)						
DC Current Gain	h _{FE}	30 60 100 100 20	300	_	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.40 -0.75	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA	
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.75 —	-0.95 -1.30	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA	
SMALL SIGNAL CHARACTERISTICS	•			•		
Output Capacitance	C _{cb}	_	8.5	pF	$V_{CB} = -10V$, $f = 1.0MHz$, $I_E = 0$	
Input Capacitance	C _{eb}	_	30	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$	
Input Impedance	h _{ie}	1.5	15	kΩ		
Voltage Feedback Ratio	h _{re}	0.1	8.0	x 10 ⁻⁴	$V_{CE} = -10V, I_{C} = -1.0mA,$	
Small Signal Current Gain	h _{fe}	60	500	_	f = 1.0kHz	
Output Admittance	h _{oe}	1.0	100	μS		
Current Gain-Bandwidth Product	f _T	200	_	MHz	$V_{CE} = -10V, I_{C} = -20mA,$ f = 100MHz	
SWITCHING CHARACTERISTICS						
Delay Time	t _d	_	15	ns	V _{CC} = -30V, I _C = -150mA,	
Rise Time	t _r		20	ns	$V_{BE(off)} = -2.0V, I_{B1} = -15mA$	
Storage Time	ts	_	225	ns	V _{CC} = -30V, I _C = -150mA,	
Fall Time	t _f		30	ns	$I_{B1} = I_{B2} = -15\text{mA}$	

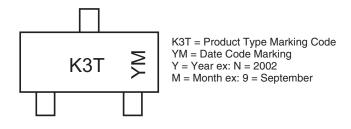
Ordering Information (Note 4 & 6)

Device	Packaging	Shipping			
MMST4403-7-F	SOT-323	3000/Tape & Reel			

Notes: 4. Product manufactured with Date Code 0609 (week 9, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0609 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

- 5. Short duration test pulse used to minimize self-heating effect.
- 6. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

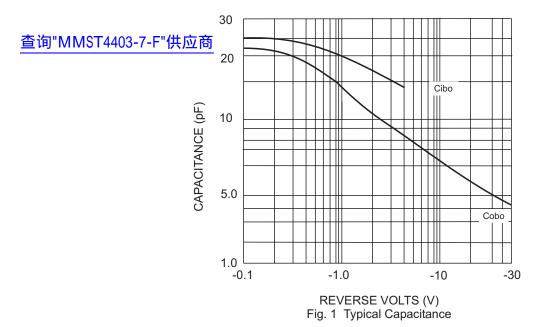
Marking Information



Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009
Code	J	K	L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

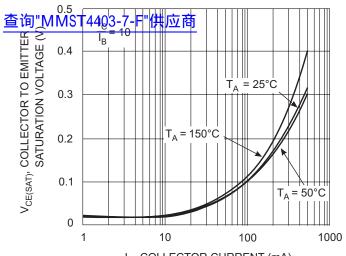




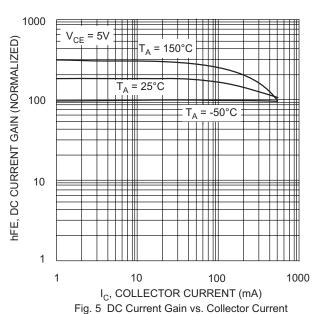
1.6 V_{CE} COLLECTOR-EMITTER VOLTAGE (V) 1.4 I_C = 100mA $I_C = 1mA$ I_C = 300mA 1.2 I_C = 30mA 1.0 8.0 0.6 0.4 0.2 0 0.001 0.01 0.1 10 100

 $\rm I_B$ BASE CURRENT (mA) Fig. 2 Typical Collector Saturation Region



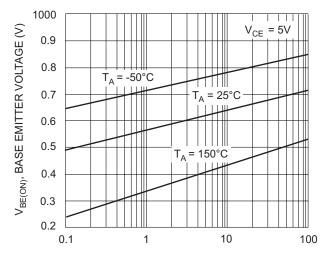


I_C, COLLECTOR CURRENT (mA)
Fig. 3 Collector Emitter Saturation Voltage
vs. Collector Current



350 P_D, POWER DISSIPATION (mW) 300 250 200 150 100 50 0 0 25 50 75 100 125 150 175 200 T_A, AMBIENT TEMPERATURE (°C)

Fig. 7, Max Power Dissipation vs Ambient Temperature



I_C, COLLECTOR CURRENT (mA) Fig. 4 Base-Emitter Voltage vs. Collector Current

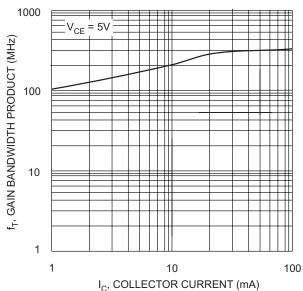


Fig. 6 Gain Bandwidth Product vs. Collector Current



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